INSTRUCTION MANUAL FTV-250

YAESU MUSEN CO., LTD.

TOKYO JAPAN

FTV-250

TWO METER TRANSVERTER



The Model FTV-250 is an all solid-state two meter transverter designed for two meter operation in conjunction with the FT-101/277, FL-101/FR-101 or FT-201 series HF transceiver.

Advanced solid-state circuit offers unsurpassed stability and clean signals at an input of 20 watts on 144 through 148 MHz. The spurious radiations are extremely reduced or eliminated by the use of dual balanced mixer in the exciter stage.

The low noise and high gain dual-gates MOS FET provides superior receiver front end.

The entire two meter band is devided into two segments which are selected by a switch on the front panel. The switch also selects HF and VHF antenna automatically.

The transverter is self-contained. It may be operated from 100/110/117/200/220 or 234 volt 50/60 Hz AC when the power transformer is appropriately wired. The FTV-250 is normally supplied for 117 volt AC and 12 volt DC operation.

The transverter weighs approximately 6 kg and is 210 m/m wide, 150 m/m high and 290 m/m deep.

SPECIFICATIONS

TRANSMITTER

Input Frequency 28 - 30 MHz

Input Voltage 3 Volts RMS

Input Impedance Approximately 8 kilo ohms

PA Input 20 watts DC

Output Frequency 144 - 148 MHz

Output Impedance 50 ohm unbalanced

Spurious Radiation Better than -60 dB

RECEIVER

Input Frequency 144 - 148 MHz

Antenna Impedance 50 ohm unbalanced

Sensitivity SSB/CW: Better than S/N 20 dB at 0.5 u

Volt antenna input signal

AM: Better than S/N 10 dB at 1 u Volt

antenna input signal

Internal Spurious Better than 0 dB

Output Frequency 28 - 30 MHz

Output Impedance 50 ohms

Power Requirements 100/110/117/200/220/234 Volt 50/60 Hz AC

or 13.5 Volt DC negative ground

Power Consumption AC 0.75 VA

DC 2.6 A at 10 watts antenna output

Size 210 (W), 150 (H), 290 (D) m/m

Weight Approximately 6 kg

*The above values are in conjunction with FT-101E.

SEMICONDUCTORS

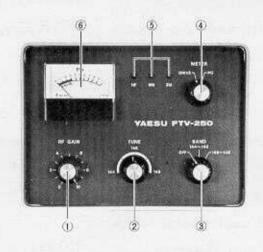
FET			
2SK19GR	3	2SK19Y	1
3SK40M	1		
SI TRANSISTOR			
2SC372Y	2	2SC373	1
2SC730	1	2SC735Y	1
2SC741	1	2SC784R	3
2SD313D	2	2N3055	1
2N5591	1	MRF208	1
GE DIODE			
1N60AM	2	1S188FM	1
SI DIODE			
181555	5	151941	3
10D-1	3	DS-130YD	1
M4B-5	1		
ZENER DIODE			
1N4740	1	WZ061	1
WZ090	1	WZ110	1
VARACTOR DIODE			
1S1658	2	BB105GM	7
LED			
SL103	3		

ACCESSORIES

AC Power Cord	1	Coaxial Plug MP-7	1
Coax. Cable (A)	1	Fuse 2A	1
Coax. Cable (B)	1	DC Cord is optional.	
Coax. Cable (C)	1		

CONTROLS AND SWITCHES

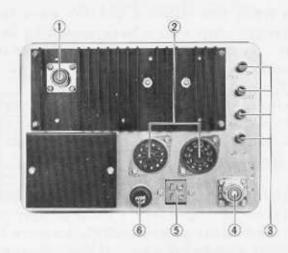
FRONT PANEL



- (1) RF GAIN The RF GAIN controls the gain of RF amplifier stage.
- (2) TUNE This control tunes the signal circuit for both transmitter and receiver for optimum performance.
- (3) BAND

 The BAND switch is a three position switch that selects the two meter amateur band. In the OFF position, the FTV-250 transverter is inoperative and the HF or six meter transverter, if used, will become operational. If the BAND switch of six meter transverter, when connected, is also in the OFF position, the HF antenna is automatically connected to the HF equipment.
- (4) METER This switch selects the meter mode to read exciter drive level and a relative power output.
- (5) HF 6M 2M The lamp shows the band in use.
- (6) METER The METER indicates the relative power output and drive level.

REAR PANEL



- (1) 2M ANT Two meter antenna is connected here.
- (2) 2M 6M Refer to the interconnection diagram.
- (3) TRX (IN-OUT), 6M (TX-RX)

 RF input and output connectors. Refer to the interconnection diagram.
- (4) HF ANT HF antenna is connected here. If FTV-650B is also connected, the HF antenna is connected to the FTV-650B as illustrated in the interconnection diagram.
- (5) POWER Power receptacle. AC power cord is supplied with the transverter.
- (6) FUSE Fuse holder. For AC operation, a 1 amp fuse is used for 100/117 volt and 0.5 amp fuse on 200/234 volt operation.

INSTALLATION

The FTV-250 Transverter has been primarily designed for combination use with our FT-101/FT-201 transceivers and FL-101/FR-101 transmitter/receiver. The power supply is selfcontained.

The transverter should be placed in a location that has adequate space to permit free air circulation around the heat sink on the back panel.

The antenna and its location are the most important consideration. The antenna should always be as high and in the clear as possible, and a minimum distance of 10 feet should be maintained between the VHF and other antennas.

The most popular antenna types are either a quarter wave length whip with unity gain or a 5/8 wave length whip with a base matching device affording approximately 3.5 dB gain. A multi-element Yagi antenna is also widely used for DX communications.

To minimize loss in the antenna system, the use of the shortest length of the coaxial cable that is practical is recommended, avoiding any sharp angles or kinks. Use type RG-8U cable if the cable length exceeds 25 feet, while RG-58/U may be used for shorter lengths.

The transverter is designed for use in many areas of the world where the supply voltage may differ from the operator's local supply voltage. Therefore, before connecting the AC cord to the power outlet, be sure that the transformer windings agree with the local supply voltage. If not, please refer to Figure 1 for rewiring of the transformer primary connections.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IMPROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSVERTER. OUR WARRANTY DOES NOT COVER DAMAGES CAUSED BY SUCH IMPROPER SUPPLY VOLTAGE.

Be sure proper fuse is used according to the local supply voltage; 1 amp for 100 - 117 volts and 0.5 amp for 200 - 234 volts.

For DC operation, use the DC power cord which may be available through your dealer.

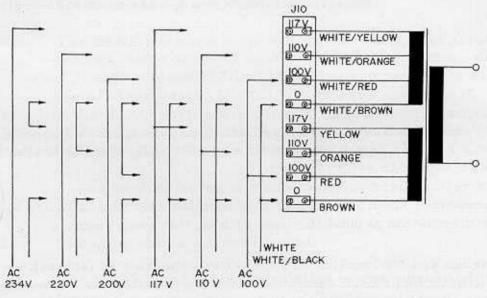


Figure 1 Transformer Primary Wiring

INTERCONNECTIONS

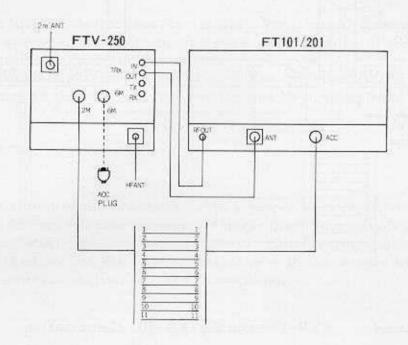


Figure 2 FTV-250 and TRANSCEIVER Combination

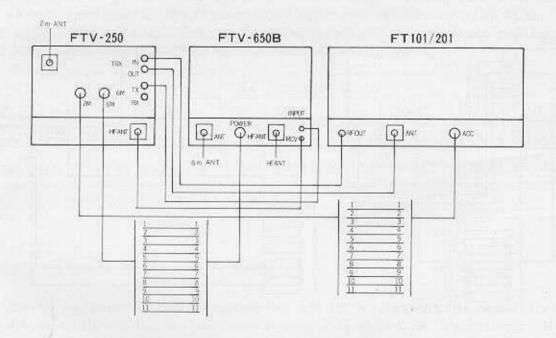


Figure 3 FTV-250, FTV-650B and TRANSCEIVER Combination

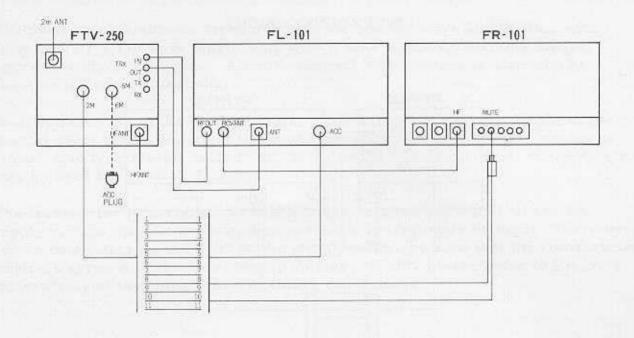


Figure 4 FTV-250 and FL/FR-101 Combination

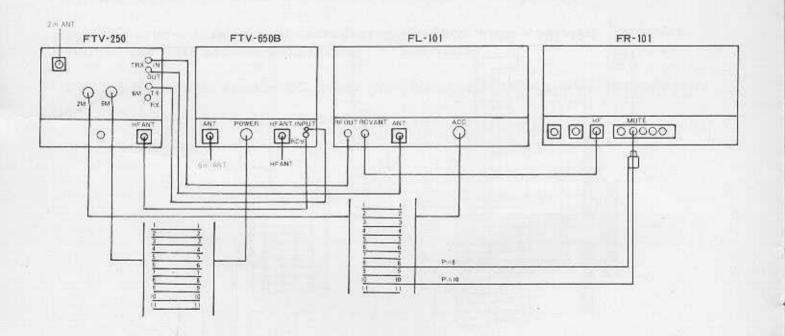


Figure 5 FTV-250, FTV-650B and FL/FR-101 Combination

OPERATION

The tuning procedure of the transverter is not complicated, however, care should be exercised when tuning to insure peak performance of the two combined equipments, transverter and HF equipment.

The following paragraphs describe the procedures for receive and transmit tuning. It is assumed that the interconnection has been completed as shown on page 7 and 8.

INITIAL CHECK

Refer to the connection of the transverter to a power source, and carefully examine the unit for any visible damage. Check that the controls and switches are operating normally. Ensure that the power transformer winding (voltage specification marked on the rear panel) matches with the supply voltage. Ensure that the interconnection has been completed.

FREQUENCY SELECTION

The frequency is determined by the main tuning dial of the HF equipment in conjunction with the transverter BAND switch setting. The transverter BAND switch selects two bands, 144 through 146 MHz and 146 through 148 MHz. The HF equipment covers 2 MHz in four segments. The frequency relation between the transverter and the HF equipment is as follows;

	HF Equipment							
TRANSVERTER	10 A	10 B	10 C	10 D				
144 - 146 MHz	144.0-144.5	144.5-145.0	145.0-145.5	145.5-146.0				
146 - 148 MHz	146.0-146.5	146.5-147.0	147.0-147.5	147.5-148.0				

Table 1

RECEIVE

Set the BAND switches of both transverter and HF equipment for the desired band and tune to the signal by the main tuning dial of the HF equipment. Peak the TUNE control for maximum S-meter reading on the HF equipment. Adjust the RF GAIN of the transverter to reduce interferences from strong signals.

TRANSMIT

CAUTION:

A DUMMY LOAD OR ANTENNA SHOULD BE CONNECTED TO THE ANTENNA TERMINAL FOR TUNE UP OF THE TRANSVERTER OR THE HF EQUIPMENT.

Set the transverter BAND switch to OFF position. Prior to tuning the transverter, the HF equipment must be tuned to 10 meter band with a dummy load connected to the HF antenna terminal of the transverter. Tune up the HF equipment into the dummy load at the desired frequency given from Table 1.

After completion of the HF equipment tune up, set the MIC GAIN and CARRIER controls to fully counterclockwise position, O mark. Set the transverter BAND switch to the desired band and the METER switch to DRIVE position.

Set the HF equipment to TUNE position and set the HF equipment to the transmit mode by the PTT switch. Increase the CARRIER control until the transverter meter reading starts to increase. Peak the PRESELECTOR of the HF equipment and the DRIVE control of the transverter for maximum meter reading. Adjust the CARRIER control until the meter indication stays in the top of the green portion of the meter scale at maximum drive. Set the MODE switch to SSB mode. (Usually the USB mode is used in 2 meter band.)

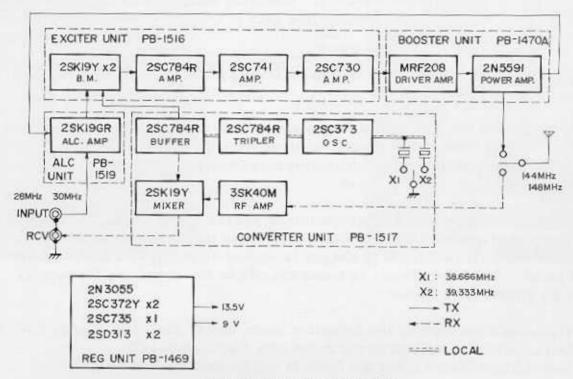
Advance MIC GAIN until the meter indication goes up to the upper limit of the green portion on voice peaks when speaking normally into the microphone. On AM mode, the CARRIER LEVEL should be set to the 20% of PO indication on CW mode with the METER switch at PO position.

The MIC GAIN should be set at a level where the meter indication kicks up slightly, with voice peaks.

It is recommended to set the METER switch to the DRIVE position and observe the meter indication so as not to exceed the green portion during operation. Excessive drive may cause the distortion and splatter.

CIRCUIT DESCRIPTION

The following block diagram and circuit description will provide you with better understanding of the transverter.



FTV-250 BLOCK DIAGRAM

RECEIVER

The 144 MHz input signal from the antenna is fed through an antenna relay, RL1201 to pin 5 of the CONVERTER UNIT, PB-1517. The signal is amplified by the RF amplifier Q401, 3SK40M, dual gate MOS FET, and then fed to the gate of the mixer Q402, 2SK19Y, where the input signal is heterodyned with a local signal into 28 MHz IF signal.

The input and output circuits of the RF amplifier utilize a double tuned circuit, which is sharply tuned to the frequency of the received signal with the varactor diodes D401 through D404. Voltage to BB-105-GM is controlled by the TUNE control on the front panel, thus reducing cross and intermodulation.

The heterodyne crystal oscillator Q403, 2SC373, oscillates at 38.66 MHz for 144 - 146 MHz or 39.33 MHz for 146 - 148 MHz depending upon the BAND switch position. This signal is fed to the trippler Q404, 2SC784R, producing 116 or 118 MHz heterodyne signal. The heterodyne signal is fed through the buffer amplifier Q405, 2SC784R, to the receiver mixer 2SK19Y and the exciter mixer 2SK19Y. The converted 28 through 30 MHz IF signal is tuned by T401 and a varactor diode 1S1658 and then fed through the antenna change-over relay to the output terminal J5.

TRANSMITTER

The 28 MHz signal from the RF output of the HF transmitter is fed through the antenna relay to pin 6 of ALC AMP UNIT, PB-1519. The 28 MHz signal is amplified by the ALC (Automatic Level Control) amplifier Q501, ZSK19GR, and fed to the EXCITER UNIT, PB-1516. The ALC voltage is fed through pin 7 to the gate circuit of Q501 and reduces the gain of Q501 to prevent distortion caused by over drive.

A part of the input signal is rectified by D501 and D502, 1S1555, and used to indicate the drive level on the meter.

The output from Q501 is fed to the balanced mixer, consisting of Q601 and Q602, 2SK19GR, where the signal is mixed with the heterodyne signal delivered to the center tap of the input transformer secondary, producing a 144 through 148 MHz signal.

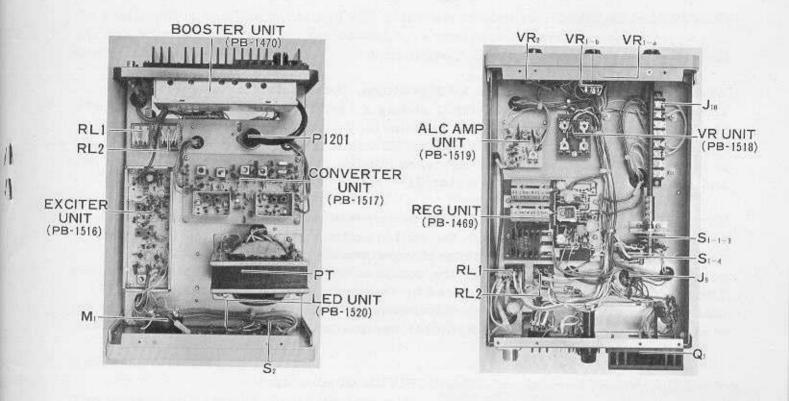
The output signal from the balanced mixer passes through tuned circuits consisting of L601, L602 and L603 which are tuned by the varactor diodes D602, D603 and D604, BB-105-GM Voltages is varied by the TUNE control from the front panel. Thus the circuit is tuned exactly to the operating frequency, reducing spurious radiation.

The signal is amplified by the amplifier chain Q603, 2SC784R, Q604, 2SC74l and Q605, 2SC730, and fed to the BOOSTER UNIT, PB-1470. The output signal level from the Q605 is approximately 0.1 watt.

The signal from the EXCITER UNIT is fed to the BOOSTER UNIT and amplified by the driver amplifier Q1201, MRF208, and the final amplifier Q1202, 2N5591, which delivers 10 watts of RF power to the antenna through two stage lowpass filter and the antenna relay.

The bias voltage is stabilized at 9 volts by a zener diode D1209, 1N4740. Two diodes D1201 and D1202, 10D1, are used to protect the power transistors from damage due to heating. A small portion of the RF output is rectified by a diode D1203, 1S188FM, which delivers a resulting DC voltage to the meter where it provides an indication of the relative power output.

The DC voltage obtained from rectifying a small portion of the RF output by the ALC diode D1204, 1S-1555, which is biased by the ALC threshold control VR-1201, is applied to the gate of Q501 in the ALC AMP unit.



Top View

Bottom View

POWER SUPPLY

The power supply has been designed to operate from 100/110/117/200/220 or 234 volts AC 50/60 Hz or 12 volts DC negative ground. Inserting the appropriate power plug into the rear panel receptacle makes the necessary connections to operate the supply in either AC or DC mode.

For AC operation, the DC voltage is supplied from the bridge connected rectifier unit D1501, M4B-5, which is connected to 17.5 volt secondary winding of the power transformer. The DC voltage is regulated at 13.5 volts by the voltage regulator circuit consisting of Q1501, 2SD313D, Q1, 2N3055 and Q1502, 2SC372Y.

The 13.5 volt voltage is further stabilized at 9 volts by the voltage regulator circuit consisting of Q1503, 2SC372Y, Q1504, 2SD313D and Q1505, 2SC372Y and supplied to the receiver circuit and the heterodyne oscillator circuit.

For DC operation, the positive voltage is connected to pin 3 and the negative voltage to pin 4 of the power receptacle. To protect the circuit from reverse connection of the DC voltage, D2, DS130YD, conducts heavily with reverse polarity connection to blow the line fuse in the DC cord.

CONTROL CIRCUITS

(1) FTV-250 and TRANSCEIVER Combination

When the BAND switch is in the OFF position, the supply voltage for the antenna relay RL-1 is disconnected, and as a result, DC or AC supply voltage for FTV-250 is disconnected. HF antenna is directly coupled through the relay contacts and J5 (TRX OUT) to the HF transceiver. 12.6 volts is supplied to heat up the final tubes of the HF transceiver, connecting pin 2 of J2 (2M) and J3 (6M) through the fourth wafer S1-4 of the BAND switch.

When the BAND switch is at 144 - 148 MHz positions (2 meter operation) the relay voltage is supplied through the switch and the relay activates for 2 meter operation, connecting the HF transceiver antenna jack, J5 to the 28 MHz IF output of the transverter through the contacts of the antenna relay RL-2. The antenna relay RL-2 is controlled by transmit-receive operation of the HF transceiver. The RL-2 supplies 9 volts for the receiver section on receiver mode and 13.5 volts for the transmitter section on transmit mode.

(2) FTV-250, FTV-650B and TRANSCEIVER Combination

In this combination, the HF antenna is connected to the 6 meter transverter and HF antenna terminal of the FTV-250 is connected to RCV jack of the FTV-650B as illustrated in the interconnection diagram. With the BAND switch at OFF position, the HF transceiver can be operated as described above and, in addition, 6 meter transverter can be operated as follows:

Signal from the HF antenna is fed to the HF transceiver through RCV jack of FTV-650B, J8 (HF ANT), RL-1 and J5 (TRX OUT). On transmit, on 6 meter band, 28 MHz signal from the HF transceiver is fed through J4 (TRX IN), RL-1 and J6 (6M TX) to the input terminal of the FTV-650B.

When the BAND switch of FTV-650B is OFF, the FTV-250 operates as described in the above paragraph.

MAINTENACE & ALIGNMENT

The FTV-250 transverter has been carefully aligned and tested at factory prior to shipment. With normal usage, it should not require other than the usual attention given to electronic equipment. Service or replacement of major parts may require subsequent realignment, but under no circumstances should realignment be attempted unless the operation of the transverter is fully understood,

the malfunction has been analized and definitely traced to misalignment. Service work should only be performed by experienced personnel using proper test equipment.

TEST EQUIPMENT REQUIRED

- (1) RF Signal Generator with 1 volt output at an output impedance of 50 ohms and a frequency coverage to 150 MHz.
- (2) Vacuum Tube Volt-Ohm-Meter (VTVM). Hewlett-Packard Model 401B, or equivalent with an RF probe workable up to 150 MHz.
- (3) Dummy Load, Yaesu YP-150, or equivalent with 50 ohm nonreactive load rated at 20 watt average power.
- (4) Frequency Counter, YC-355D, or equivalent workable up to 200 MHz.

REGULATOR UNIT, PB-1469

The voltage adjustment should be done with AC power supply.

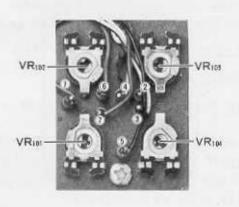
13. 5 volts; Connect a VTVM DC probe between the 13. 5 volt terminal (positive) and ground (negative). Adjust VR1501 for exact 13. 5 volt reading on the VTVM.

9 volts: Connect a VTVM DC probe between the 9 volt terminal (positive) and ground (negative) and adjust VR1502 for exact 9 volt reading on the VTVM.

REG UNIT

VR UNIT, PB-1518

Set the TUNE control to 148 MHz setting. Connect the positive probe of VTVM to the center arm of forward potentiometer VRIa (TUNE control pot) located on front panel, and adjust VR104 for 5.5 volt reading on the VTVM. Set the TUNE control to 144 MHz setting and make sure that the voltage drops to 3 volts. Disconnect the VTVM positive probe and connect it to the center arm of rear potentiometer VR1b (TUNE control pot). Set the BAND switch to 146 - 148 MHz segment and the TUNE control to



VR UNIT

148 MHz setting. Adjust VR101 for 4.3 volt on the VTVM. Set the TUNE control to 146 MHz and read the VTVM reading.

Set the BAND switch to 144 - 146 MHz segment and the TUNE control to 144 MHz. The VTVM reading should be same as the value measured at 146 MHz with the BAND switch setting of 146 - 148 MHz. Set the TUNE control to 146 MHz. The VTVM should read 4.3 volt.

If these values are not the same, adjust VR102 and VR103 alternately until the VTVM shows the same value at both high and low ends of both band segments.

CONVERTER UNIT, PB-1517

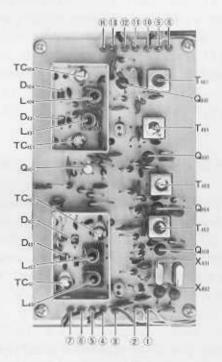
(1) Heterodyne Oscillator

Connect the VTVM RF probe to the base of Q404 and peak T402 for maximum VTVM reading, and set the T402 where the VTVM shows 80% of maximum reading.

Connect the VTVM RF probe and frequency counter to the base of Q405 and peak T403 for maximum VTVM reading.

Connect the VTVM RF probe to pin 8 and peak T403 for maximum VTVM reading.

The coils should be adjusted until the VTVM reading shows the same value with the BAND switch setting of 144 - 146 MHz and 146 - 148 MHz. The output frequency should be 116 MHz for 144 - 146 MHz and 118 MHz for 146 - 148 MHz band.



CONVERTER UNIT

(2) Receiver Front End

Prior to this alignment, the VR unit should be realigned as described in the preceding paragraph. Connect the output of the signal generator set at 146 MHz to the antenna connector.

Set the controls and switch as follows.

BAND 144 - 146 MHz

TUNE 146 MHz

RF GAIN Fully clockwise position

Peak TC401, TC402, TC403, TC404 and T401 for maximum S-meter reading. After above procedures, make sure that the TUNE control indication matches to the frequency on the front panel when the receiver is tuned to 144 MHz and 146 MHz respectively.

Set the BAND switch to 146 - 148 MHz segment, and make sure that the TUNE control indicates 146 MHz, 147 MHz and 148 MHz when the receiver is tuned to these frequency respectively.

ALC AMP UNIT, PB-1519

Set the METER switch of FTV-250 to DRIVE position and the controls of the HF transceiver as follows.

BAND

10B

FREQUENCY

29 MHz

MODE

TUNE

CARRIER

0

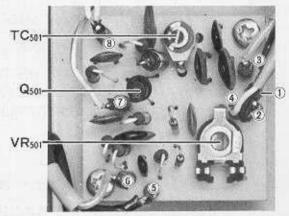
Tune up the HF transceiver at 29 MHz and connect the VTVM RF probe to pin 6 of PB-1519. Increase the CARRIER control until the VTVM indicates 3 volt RMS. Connect the VTVM RF probe to pin 3 and peak TC501 for maximum VTVM reading.

Adjust VR501 until the meter shows 0.3 in the green scale.

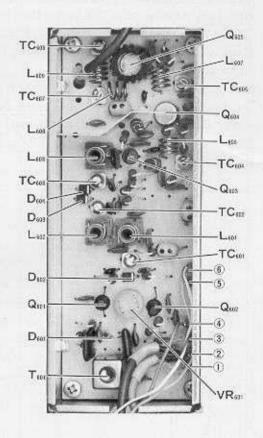
EXCITER UNIT, PB-1516

Set the HF transceiver to the same condition as ALC AMP alignment. Set the TUNE control to 145 MHz and the BAND to 144 - 146 MHz. Connect the RF probe of VTVM to the RF input terminal of the BOOSTER UNIT. Peak TC601 through TC607 and T601 for maximum VTVM reading. Connect the VTVM RF probe to the hot end of L602 (junction point between L602 and C614). Adjust VR601 for minimum VTVM reading.

TC601 through TC607 should be realigned for maximum power output at 146 MHz after the completion of the BOOSTER UNIT realignment.



ALC AMP UNIT



EXCITER UNIT

BOOSTER UNIT, PB-1470

Set the controls and switches as follows:

HF Transceiver

BAND

10 D

FREQUENCY

30 MHz

MODE

TUNE

CARRIER

At the level which gives 3 volt (RMS) RF input at

FTV-250 RF input.

FTV-250

BAND

144 - 146 MHz

TUNE

146 MHz (12 o'clock position)

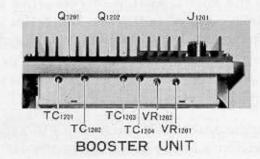
It is assumed that the FTV-250 alignment is completed, except the BOOSTER UNIT. Set the VR1201 and VR1202 to fully counterclockwise position. Connect the RF probe of VTVM to the base of Q1201 and peak TC1201, and TC605 and TC607 in the EXCITER UNIT for maximum VTVM reading.

Connect the RF probe of VTVM to the base of Q1202 and peak TC1202 for

maximum VTVM reading.

Set the METER switch of the FTV-250 to PO position and peak TC1201, TC1202, TC1203 and TC1204 for maximum meter indication. Adjust VR1201 until the power meter (dummy) shows exactly 10 watts.

Set the METER switch to PO position and adjust VR1202 until the meter indicates 0.8 at 10 watts output.



CONNECTOR RESISTANCE CHART

UNIT	PIN	1	2	3	4	5	6	7	8	9	10	11	12	13	14
	J ₁	00	œ	00	Е	-	-	-	=	-	-	-	in the	-	-
MAIN CHASSIS	J ₂	550K	oo	00	100	00	00	00.	Е	4.6K	00	00	-	-	-
	Ja	600K	00	00	00	60	00	00	E	10K	00	130K	HES.	20	-
REG		82	95	95	50	28	10	10	W.	225				770	-
CONVER- TER		500K	500K	82	Е	0	E	82	0	82	E	0	Е	₩ 3K	₩ 18K
ALC AMP		E	E	00	₩ 1.2K	Е	22K	180K	13	-	2		441	27	-
EXCITER		00	É	0	≋ 3K	₩ 18K	13	_	-		-	Line.		-	35
BOOSTER	J ₉	E	0	₩ 3K	₩ 1.7K	82	13	13	-	-	43	-	4		-

POWEROFF
BANDOFF
RF GAINMAX
METER SWITCH....PO

Measured with 20 k ohm/V. Values are in OHM.

VOLTAGE CHART

UNIT		E	(S)	C	(D)	В	(G)	HAUT	+	E	(S)	С	(D)	В	(G)			
OMI		R	Т	R	Т	R	Т	UNIT		R	Т	R	Т	R	Т			
MAIN CHASSIS	Q ₁	13.5	13.5	18.0	18.0	14.0	14.0	ALC AMP	Q501	0	0.95	0	13.0	0	0			
	Q ₁₅₀₁	14.0	14.0	18.0	18.0	14.6	14.6 14.6		Q601	0	1.75	0	12.5	0	0			
	Q1302	9.0	9.0	14.6	14.6	9.6	9.6	EXCI- TER	6		9.6	Q502	0	1.75	0	12.5	0	0
REG	Q1503	9.6	9.6	13.5	13.5	10.2	10.2		Q603	0	1.25	0	13.0	0	1.9			
	Q ₁₅₀₄	9.0	9.0	13.5	13.5	10.2	10,2		Q604	0	0.75	0	13.0	0	1.65			
	Q ₁₅₀₅	6.0	6.0	10,2	10.2	6.4	6.4		Q005	0	0	0	13.0	0	0.6			
	Q401	2.9	0	9.0	0	G ₁ 0.8 G ₂ 4.4	0.	BOOS- TER	Q ₁₂₀₁	0	0	0	13.0	0	0.7			
	Q402	1.7	0	9.0	0	0	0.		Q1202	0	0	0	13.0	0	0.7			
CONVER- TER	Q403	1.5	1.5	8.3	8.3	1.54	1.54											
	Q494	0,85	0.85	8.5	8.5	0.24	0.24											
	Q405	0.8	0.8	8.5	8.5	1,2	1.2											

Measured with VTVM. Values are in VOLT DC.

FTV-250 PARTS LIST

			PRINTED CIRCUIT BOARD	
22/24/20	2000	For toot	INO UZUZANOS	
7-4452 -4452		403, 404	CONVERTER UNIT	
5-4423		101		-
GORY	SEORMER			_
	03110030		1001-NS	
			FUSE HOLDER	Н
Hml	KEC	Z01 '901		-
S20"tH	REC	011	1918-JM	0
H#01	BEC	402	X142.6S	
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	424, 426, 428		VD3844	2
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94/100.0 VWO		415, 420, 425		
0MA I20PF(CH)		214	AP3241	2
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0MA 50PF(CH)		403, 414, 421		
0MA 12bE(CH)		624	47820C1	
0MA ISEE(CH)	g	427, 432	METER	V
0MA 25E(CH)	413 2	401, 402, 411,		
0MA 35E(CH)	g	437, 438	97-79	1100
OSIC	CERAMIC I	C CAPAC	POWER TRANSFORMER	1
			S2MA S50"H	
SIM1 M	M 414,114	401, 402, 410,	ELECTROLYTIC	
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M 3' 3 K 5 5 K 7	K K K K K	413, 420 413, 430 409, 417, 424 428 428	CAPACITOR EWF-POAS 15098 5KB/50KB	ъ'
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M 3' 3 K 5 5 K 7	426 K 426 K 426 K CVBBON FI	415, 418, 422, 425, 429 408, 421 413, 430 420, 417, 424 428	CEBAMIC DISC CAPACITOR EWF.POAS 15098 5KB/50KB EVT.BOAS 15B53 5KB	ъ '9
M 3' 3 K 5 5 K 7	426 K 426 K 426 K CVBBON FI	415, 418, 422, 425, 429 408, 421 413, 430 420, 417, 424 428	CEBVMIC DISC CVANCILOB EME:DOVS 12038 2KB\20KB EAT:BOVS 12038 2KB\20KB EAT:BOVS 12038 2KB\20KB BOLENLIOWELEB SM 1203 MIKE MOUND	ъ '9 '
M 3' 3KG M 5' 5KG M 5' 5KG M 55065 M 55065 M 10065	TOR CARBON FI 426 以 426 以 426 以 14	428 409, 417, 424 415, 429 415, 429 415, 429 415, 429 415, 429 415, 429 415, 429	CEBVMIC DISC CVANCILOB EME-BOVS 12038 2KB\20KB EAT-BOVS 12B23 2KB BOLENLIOWELEB SM 1203 AIBE MODIAD NM	ъ '9 '
39. 3333MHz M 3. 28023 M 5. 2802 M 5. 2803 M 5. 2803 M 1. 6803 M 10002	大	402 402 409, 417, 424 413, 430 415, 429 415, 429 415, 429 415, 429 415, 420 400, 421 415, 420 400, 400	CEBVMIC DISC CVBVCILOB EME:BOVZ 12038 2KB\20KB EAT:BOVZ 12038 2KB\20KB EAT:BOVZ 12038 2KB\20KB BOLENLIOWELEB SM 1203 AIBE MOUND NM 410KG NM 450KG	8 9
38, 6666MHz 39, 3333MHz W 2, 2KΩ W 2, 2KΩ W 2, 2KΩ W 1, 5KΩ W 2, 2KΩ W 2, 2KΩ	模	458 400' 412' 454 408' 451 412' 450 412' 450 412' 418' 455' 405 405 401 401 401	CEBVMIC DISC CVBVCILOB EME-BOVS 12038 2KB\20KB EAT-BOVS 12938 2KB\20KB BOLENLIOWELEB SM 1203 MISE MOUND NM 450KG NM 450KG	ъ '9
М 3° 3 КС М 5° 5 КС М 5° 5 КС М 5° 5 КС М 5° 5 КС М 1005 М 1005 М 1005 38° 6666МН× 38° 6666МН× 38° 6666МН×	Agractor BH TOSS/U HC25/U HC25/U AL AL AL BL BL BL BL BL BL BL BL BL BL BL BL BL	458 400' 412' 454 400' 412' 454 400' 451 412' 418' 455' 405 401 401 401 401 401 401 401 401	CEBVMIC DISC CVBVCILOB EAL: DOVE 12038 SKB\20KB EAT: BOVE 12938 SKB\20KB BOLENLIOWELEB SM 1203 AIBE MOUND NM 420KG NM 420KG NM 1KG	.6 .6
М 3° 3 КС М 5° 5 КС М 5° 5 КС М 55065 М 55065 М 10065 М 10065 М 28066 М 28066 М 38066 М 10065 М 10065 M 10	Varactor 15 Varactor BHC25/U HC25/U	458 450 450 400' 412' 454 412' 430 412' 456 412' 456 405 401 401 401 401 401 401 401 402	CEBVMIC DISC CVBVCILOB EME-BOVS 12038 2KB\20KB EAT-BOVS 12938 2KB\20KB BOLENLIOWELEB SM 1203 MISE MOUND NM 450KG NM 450KG	B.
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M 3' 3RC M 5' 5RC M 6' 6RC M 6' 6RC M 7' 6RC M 7	Co IN Varactor IS Varactor II Varactor IS Varactor II	458 400' 412' 454 412' 430 408' 451 412' 450 412' 418' 455' 401 401 401 401 401 401 402 402 402 402 406' 402 406' 402	CEBVMIC DISC EME-BOVZ 12038 2KB\20KB EAT-BOVZ 12038 2KB\20KB EAT-BOVZ 12038 2KB\20KB BOLENTIOWETER SM 1203 WIRE MOUND SM 470KG SM 470KG SM 1KG MRE MOUND SM 1KG MRE MOUND SM 1KG SM 1203 SM 1KG SM 1203 SM 1KG SM 1203 SM 1203 SM 1203 SM 1203 SM 1203 SM 1203	9 '9 '9 '9 '9 '9 '9 '9 '9 '9 '9 '9 '9 '9
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THE PERSON NAMED IN	(A-Z)	D CIRCUIT B	OAHD	604, 605		50W.V	390PI
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			101(1)	602		# 22100	
C	CAPAC			603		# 22100	
		CERAMIC DIS		604, 606		# 22101	
501	a limited on the limited of the limi	50W	V 10PF (CH)	605, 607, 609		# 22101	
	507	50W	V 82PF(CH)	608	PS PS /9	# 22004	
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501	INDUCT	OR RFC #220 R UNIT	0044				RD
601 PB	EXCITE PRINTE	OR RFC #220	0044	PB PRINTI 1470 (A - Z)	ED CIRCU		RD
601 PB	INDUCT	OR RFC #220 R UNIT	0044	PB PRINTI 1470 (A~Z) Q TRANS 1201	ED CIRCU SISTOR MRF-208		RD
601 PB 1516	EXCITE PRINTE (A~Z)	OR RFC #220 R UNIT D CIRCUIT BO	0044	PB PRINTI 1470 (A - Z)	ED CIRCU		RD
501 PB 1516	EXCITE PRINTE (A ~ Z) FET &	OR RFC #220 R UNIT D CIRCUIT BO TRANSISTOR	0044 OARD	PB PRINTI 1470 (A - Z) Q TRANS 1201 1202	ED CIRCU SISTOR MRF-208 2N5591		RD
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001 PB 516 2 001, 6 005 004 003 005 001 002	PRINTE (A ~ Z) FET & 602 DIODE	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Varactor 1S16 Varactor BB10 OR CARBON FILE	0044 0044 0044 0044 19GR 730 741 84R 158 156 156 168 178 188 188 188 188 188 188 18	PB PRINTS 1470 (A ~ Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1203 1205	SISTOR MRF-208 2N5591 Ge Si Si Zener	1S188FM 1S1555 10D-1 1N4740 COMPO ½W ½W ½W	OSITION 109 229 569 1209 3309
001 516 516 001, 6 005 004 003 005 001 002	PRINTE (A~Z) FET & 602 DIODE -604 RESIST	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM	0044 0044 0044 0044 0044 0044 0044 0044 041 041 058 05GM 041 058 05GM	PB PRINTI 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1202	SISTOR MRF-208 2N5591 Ge Si Si Zener	1S188FM 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W	OSITION 109 229 569 1209 3309
B 516 01, 601 01, 605 04 03 05 06 07 19, 6 18 08, 6	PRINTE (A~Z) FET & 602 DIODE -604 RESIST	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM W W W W	0044 0044 0044 19GR 130 741 784R 1588 15GM	PB PRINTS 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206	ED CIRCU SISTOR MRF-208 2N5591 Ge Si Si Zener	1S188FM 1S1555 10D-1 1N4740 COMPO ½W ½W ½W ½W ½W	OSITION 109 229 569 1209 3309
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501 516 516 516 516 516 510 516 517 518 518 518 518 518 518 518 518	PRINTE (A~Z) FET & 602 DIODE -604 RESIST(TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM MW	0044 0044 0044 19GR 30 41 84R 1884R 1002 7 56Ω 7 100Ω 7 220Ω 7 330Ω 7 2.7ΚΩ 7 3.3ΚΩ 7 4.7ΚΩ 7 15ΚΩ	PB PRINTI 1470 (A ~ Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206 VR POTEN 1202 1201 C CAPAC	Ge Si Si Zener FOR CARBON TIOMETE EVL-SOA	1S188FN 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W ½W ½W ½W	OSITION 109 229 569 1209 3309 15K9 5KI 10KF
601 516 516 516 516 516 501 505 504 505 501 505 501 505 601 605 601 605 601 605 601 605 601 605 605 605 605 606 607 608 609 609 609 609 609 609 609 609	PRINTE (A~Z) FET & 602 DIODE -604 RESIST(521	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM MW	0044 0044 0044 0044 19GR 30 41 84R 1884R 188 195GM 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 10	PB PRINTI 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206 VR POTEN 1202 1201 C CAPAC	Ge Si Si Zener FOR CARBON TIOMETE EVL-SOA EVL-SOA	1S188F) 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W ½W ½W 2W 2W 2W 2W 2W 2W 2W	OSITION 109 229 569 1209 3309 15K9 5KE 10KE
601 516 516 516 516 516 501 505 504 505 501 505 501 505 601 605 601 605 601 605 601 605 601 605 605 605 605 606 607 608 609 609 609 609 609 609 609 609	PRINTE (A~Z) FET & 602 DIODE -604 RESIST(521	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM MW	0044 0044	PB PRINTS 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206 VR POTEN 1202 1201 C CAPAC 1216 1217, 1223	Ge Si Si Zener FOR CARBON TIOMETE EVL-SOA EVL-SOA	1S188F) 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W ½W ½W 2W 2W 2W 2W 2W 2W 2W 2W 2W	OSITION 109 229 569 1209 3309 15K9 5KE 10KE
601 516 516 516 516 516 501 505 504 505 501 505 501 505 601 605 601 605 601 605 601 605 601 605 605 605 605 606 607 608 609 609 609 609 609 609 609 609	PRINTE (A~Z) FET & 602 DIODE -604 RESIST(521	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM MW	0044 0044 0044 0044 19GR 30 41 84R 1884R 188 195GM 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 10	PB PRINTS 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206 VR POTEN 1202 1201 C CAPAC 1216 1217, 1223 1201, 1205	Ge Si Si Zener FOR CARBON TIOMETE EVL-SOA EVL-SOA	1S188F) 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W ½W ½W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W	OSITION 109 229 569 1200 3309 15K9 5KF 10KF 2PF(CH) 5PF(CH) 10PF(CH)
501 516 516 516 601, 605 604 605 604 605 601 602 7 8 119, 6 118 108, 6 117 112 112 110 110 110 110 110 110	PRINTE (A~Z) FET & 602 DIODE -604 RESIST(521 -514	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM MW	0044 0044 0044 0044 19GR 30 41 84R 1884R 188 195GM 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 10	PB PRINTS 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206 VR POTEN 1202 1201 C CAPAC 1216 1217, 1223 1201, 1205 1213~1215	Ge Si Si Zener FOR CARBON TIOMETE EVL-SOA EVL-SOA	1S188FN 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W ½W ½W ½W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W	DSITION 109 229 569 1209 3309 15K9 5KF 10KF 2PF(CH) 5PF(CH) 10PF(CH) 20PF(CH)
PB	PRINTE (A~Z) FET & 602 DIODE -604 RESIST(521 314 305 503, 606, 6	TRANSISTOR FET 2SK1 Tr 2SC7 Tr 2SC7 Tr 2SC7 Si 10D-1 Varactor 1S16 Varactor BB10 OR CARBON FILM MW	0044 0044 0044 0044 19GR 30 41 84R 1884R 188 195GM 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 100Ω 10	PB PRINTS 1470 (A~Z) Q TRANS 1201 1202 D DIODE 1203 1204 1201, 1202 1209 R RESIST 1204 1201 1203 1205 1206 VR POTEN 1202 1201 C CAPAC 1216 1217, 1223 1201, 1205	Ge Si Si Zener FOR CARBON TIOMETE EVL-SOA EVL-SOA	1S188F) 1S1555 10D-1 1N4740 COMPC ½W ½W ½W ½W ½W ½W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W 2W	vI

1202, 1204, 1208, 1210	50WV	0.001 µF	1503	Zener	WZ110	
1218~1220	50WV	0.01µF	1000	escent.		
	50W V	0.047#F		- CT-1 0.00	HIDSTER SERVICE	
1.666	30 W Y	U. SHI /2 L				
			R RESI	STOR		
ELECTRO				CARBO	N FILM	TI TIVA
1203, 1207, 1209	16WV	10 nF	1509		1/4 W	2200
	A COUNTY OF THE PARTY OF THE PA	3000000111	1511		1/4 W	2702
TC TRIMMER CAPAC	CITOR		1501		14 W	330Ω
1202~1204 P-100DS		20PF	1510, 1512		¼W	470Ω
1201 ECV-1ZW		50PF	1505		¼W	560Ω
	7.22		1502		1/4 W	680Ω
			1503		¼W	820Ω
LINDUCTOR			1508		½W	1ΚΩ
	#221019		1504		½W	2. 7KΩ
	#221022		200			
	#221020					
	#221021		VR POT	ENTIOMET	FR	
1211, 1212 RFC 1210 RFC	+ 461041	22 // H		LITTOWIE		470B
1210 RFC		22///11	1301, 1302		CICION	31.043
			C CAP	ACITOR		
RL RELAY				CERAM	IC DISC	A-1000000000000000000000000000000000000
1201 LZ-2G			1507	- 0	50WV	0.01µF
COMMISSTOR				MYLAR	>	
CONNECTOR J1201 JSO-239			1504	WIYLAN	50WV	0.001µF
P1201 SI-8501			1,0079	7 7 7 7 7 1	5077	0.00201
				ELECT	ROLYTIC	30,000 100
VR UNIT			1503		25WV	100 µF
			1508		- 16WV	220 µF
PB PRINTED CIRCUIT	T BOARD		1505	A THE REST	16WV	470µF
1518 (A~Z)			1501, 1502		25WV	2200 µF
101001 21			THE PART OF THE PA			
R RESISTOR						
CARBON	FILM					
	%W	2.7KΩ				
300		5000 -00				
VR POTENTIOMETER						
104 EVL-S3AA	.0014	10KB		WIII W		
102, 103 EVL-S3AA		50KB				
101 EVL-S3AA	.0015	100KB				
LED UNIT	(Washington)					
PB PRINTED CIRCUIT	T BOARD					
1520 (A ~ Z)						
D LIGHT EMITTING	DIODE				1	10000
201-203 SL-103						
NOTE - 100 -						
R RESISTOR						
CARBON	EILM					
CARBUN		5500				
	1/4 W	560Ω 1KΩ				
203	12.135					
203	¼W	1134				
203 201, 202	¼ W	11/22				W
203	¼W	11,32				
203 201, 202 REG UNIT		TKS			*/	
203 201, 202 REG UNIT PB PRINTED CIRCUI		IKS			*/	
203 201, 202 REG UNIT PB PRINTED CIRCUI 1469 (A ~ Z)		11/24			**	
203 201, 202 REG UNIT PB PRINTED CIRCUIT 1469 (A ~ Z) Q TRANSISTOR	T BOARD	11/25			(4)	
203 201, 202 REG UNIT PB PRINTED CIRCUIT 1469 (A ~ Z) Q TRANSISTOR 1502, 1505	T BOARD	11/22			(t)	
203 201, 202 REG UNIT PB PRINTED CIRCUIT 1469 (A ~ Z) Q TRANSISTOR 1502, 1505	T BOARD	TNSS			(t/)	
203 201, 202 REG UNIT PB PRINTED CIRCUIT 1469 (A ~ Z) Q TRANSISTOR 1502, 1505 1503	T BOARD	TNSS			(t)	
203 201, 202 REG UNIT PB PRINTED CIRCUIT 1469 (A ~ Z) Q TRANSISTOR 1502, 1505 1503	T BOARD 2SC372Y 2SC735Y	Tress			*	
203 201, 202 REG UNIT PB PRINTED CIRCUIT 1469 (A ~ Z) Q TRANSISTOR 1502, 1505 1503	T BOARD 2SC372Y 2SC735Y	Tress			*	
203 201, 202 REG UNIT PB PRINTED CIRCUI 1469 (A ~ Z) Q TRANSISTOR 1502, 1505 1503 1501, 1504 D DIODE	T BOARD 2SC372Y 2SC735Y	Tress				
203 201, 202 REG UNIT PB PRINTED CIRCUI 1469 (A ~ Z) Q TRANSISTOR 1502, 1505 1503 1501, 1504 D DIODE 1501 Si	T BOARD 2SC372Y 2SC735Y 2SD313D	Trysc				

